



SI4920DY-T1-GE3 Information



For Reference Only

Part Number SI4920DY-T1-GE3
Manufacturer Vishay Siliconix

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Arrays

Description MOSFET 2N-CH 30V 8-SOIC **Package** 8-SOIC (0.154", 3.90mm Width)

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









SI4920DY-T1-GE3 Specifications

Manufacturer Part Number	SI4920DY-T1-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	8-SOIC (0.154", 3.90mm Width)
Series	TrenchFET?
FET Type	2 N-Channel (Dual)
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	-
Rds On (Max) @ Id, Vgs	25 mOhm @ 6.9A, 10V
Vgs(th) (Max) @ Id	1V @ 250μA (Min)
Gate Charge (Qg) (Max) @ Vgs	23nC @ 5V
Input Capacitance (Ciss) (Max) @ Vds	-
Power - Max	2W
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	8-SOIC (0.154", 3.90mm Width)
Supplier Device Package	8-SO
	Report errors?

SI4920DY-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

SI4920DY-T1-GE3 Payment Methods





















SI4920DY-T1-GE3 Shipping Methods













If you have any question about SI4920DY-T1-GE3, please do not hesitate to contact us!

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